BC636, BC636-16, BC638, BC640, BC640-16

High Current Transistors

PNP Silicon



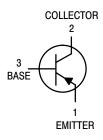
http://onsemi.com

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC636 BC638 BC640	VCEO	-45 -60 -80	Vdc
Collector-Base Voltage BC636 BC638 BC640	VCBO	-45 -60 -80	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current — Continuous	IC	-0.5	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	83.3	°C/W





CASE 29 TO-92 STYLE 14

ORDERING INFORMATION

Device	Package	Shipping
BC636	TO-92	5000 Units/Box
BC636ZL1	TO-92	2000/Ammo Pack
BC636-16ZL1	TO-92	2000/Ammo Pack
BC638	TO-92	5000 Units/Box
BC638ZL1	TO-92	2000/Ammo Pack
BC640	TO-92	5000 Units/Box
BC640ZL1	TO-92	2000/Ammo Pack
BC640-16	TO-92	5000 Units/Box

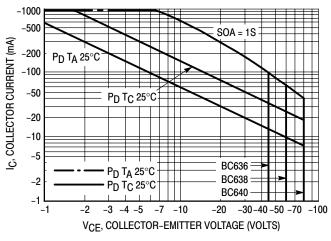
BC636, BC636-16, BC638, BC640, BC640-16

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = -10 mAdc, I _B = 0)	BC636 BC638 BC640	V(BR)CEO	-45 -60 -80	_ _ _	_ _ _	Vdc
Collector–Base Breakdown Voltage (I _C = -100 μAdc, I _E = 0)	BC636 BC638 BC640	V(BR)CBO	-45 -60 -80	_ _ _	_ _ _	Vdc
Emitter–Base Breakdown Voltage (I _E = -10 μAdc, I _C = 0)		V(BR)EBO	-5.0	_	_	Vdc
Collector Cutoff Current $(V_{CB} = -30 \text{ Vdc}, I_{E} = 0)$ $(V_{CB} = -30 \text{ Vdc}, I_{E} = 0, T_{A} = 125^{\circ}\text{C})$		СВО			-100 -10	nAdc μAdc
ON CHARACTERISTICS (1)		•				
DC Current Gain $ (I_C = -5.0 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc}) $ $ (I_C = -150 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc}) $ $ (I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V}) $	BC636 BC636–16 BC638 BC640 BC640–16	hFE	25 40 100 40 40 100 25		250 250 160 160 250	_
Collector–Emitter Saturation Voltage (I _C = -500 mAdc, I _B = -50 mAdc)		V _{CE(sat)}	_	-0.25 -0.5	-0.5 	Vdc
Base–Emitter On Voltage (I _C = -500 mAdc, V _{CE} = -2.0 Vdc)		VBE(on)	_	_	-1.0	Vdc
DYNAMIC CHARACTERISTICS						
Current–Gain — Bandwidth Product (I _C = -50 mAdc, V _{CE} = -2.0 Vdc, f = 100 MHz)		fΤ	_	150	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)		C _{ob}	_	9.0	_	pF
Input Capacitance (V _{EB} = -0.5 Vdc, I _C = 0, f = 1.0 MHz)		C _{ib}	_	110	_	pF

^{1.} Pulse Test: Pulse Width $\leq 300~\mu\text{s},$ Duty Cycle 2.0%.

BC636, BC636-16, BC638, BC640, BC640-16



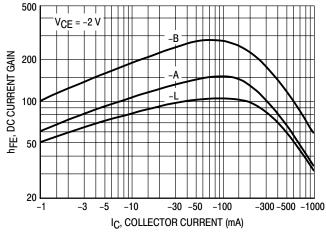
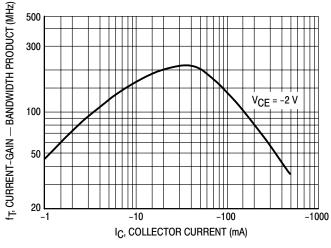


Figure 1. Active Region Safe Operating Area

Figure 2. DC Current Gain



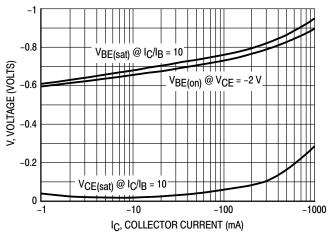


Figure 3. Current Gain Bandwidth Product

Figure 4. "Saturation" and "On" Voltages

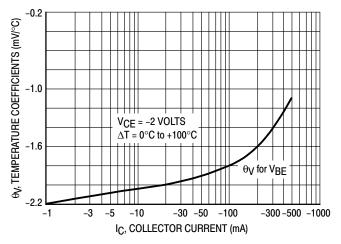
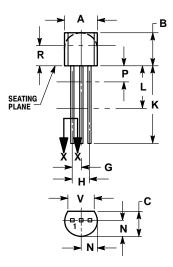


Figure 5. Temperature Coefficients

BC636, BC636-16, BC638, BC640, BC640-16

PACKAGE DIMENSIONS

TO-92 (TO-226)CASE 29-11 **ISSUE AL**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

STYLE 14:

PIN 1. EMITTER

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